NSN 5961-01-249-8303

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-249-8303 **Inclosure Material:** Glass **Overall Length:** 0.650 inches **Terminal Length:** 0.600 inches **Overall Height:** 0.450 inches **Overall Width:** 0.450 inches **Function For Which Designed:** Transient suppressor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 320.0 breakdown voltage, dc **Current Rating Per Characteristic:** 5.00 microamperes limiting current **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Precious Material And Location:** External surfaces silver **Precious Material:** Silver **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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